

DC COMPONENTS CO., LTD.

RECTIFIER SPECIALISTS

KBK6A THRU KBK6M

TECHNICAL SPECIFICATIONS OF SINGLE-PHASE SILICON BRIDGE RECTIFIER VOLTAGE RANGE - 50 to 1000 Volts CURRENT - 6.0 Amperes

FEATURES

- * Low leakage
- * Low forward voltage
- * Surge overload rating: 170 Amperes peak

MECHANICAL DATA

* Case: Molded plastic

* Epoxy: UL 94V-0 rate flame retardant

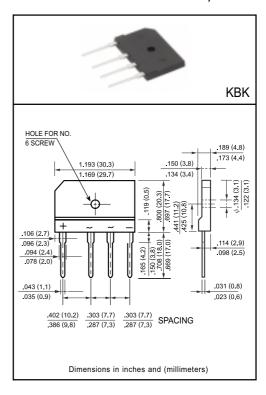
* Terminals: MIL-STD-202E, Method 208 guaranteed

* Polarity: Symbols molded or marked on body

* Mounting position: Any * Weight: 6.6 grams

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25 °C ambient temperature unless otherwise specified. Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate current by 20%.



		SYMBOL	KBK6A	KBK6B	KBK6D	KBK6G	KBK6J	KBK6K	KBK6M	UNITS
Maximum Recurrent Peak Reverse Voltage		VRRM	50	100	200	400	600	800	1000	Volts
Maximum RMS Bridge Input Voltage		VRMS	35	70	140	280	420	560	700	Volts
Maximum DC Blocking Voltage		VDC	50	100	200	400	600	800	1000	Volts
Maximum Average Forward Output Current at Tc = 100°C		lo	6.0						Amps	
Peak Forward Surge Current 8.3 ms single half sine-wave superimposed on rated load (JEDEC Method)		IFSM	170						Amps	
Maximum Forward Voltage Drop per element at 3.0A DC		VF	1.0						Volts	
Maximum DC Reverse Current at Rated	@TA = 25°C	l _R	10							uAmps
DC Blocking Voltage per element	@TA = 100°C	T "K	500							
I ² t Rating for Fusing (t<8.3ms)		l²t	120						A ² Sec	
Typical Junction Capacitance (Note1)		Cı	55						pF	
Typical Thermal Resistance (Note 2)		RθJA	21						°C/W	
Operating Temperature Range		TJ	-55 to + 150						۰C	
Storage Temperature Range		Tstg	-55 to + 150							٥C

NOTES: 1.Measured at 1 MHz and applied reverse voltage of 4.0 volts

2. Thermal Resistance from Junction to Case per element Unit mounted on 300x300x1.6mm Aluminum plate heat-sink.

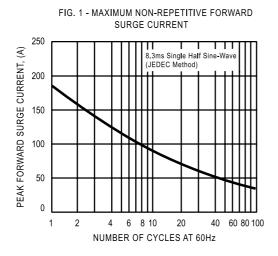


FIG. 2 - TYPICAL FORWARD CURRENT DERATING CURVE

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Single Phase Half Wave 60Hz Indutive or Resistive Load

CASE TEMPERATURE, (°C)

